

# SE2AD THRU SE2MD

## SURFACE MOUNT HIGH EFFICIENT RECTIFIERS

Reverse Voltage - 50 to 1000 V  
Forward Current - 2 A

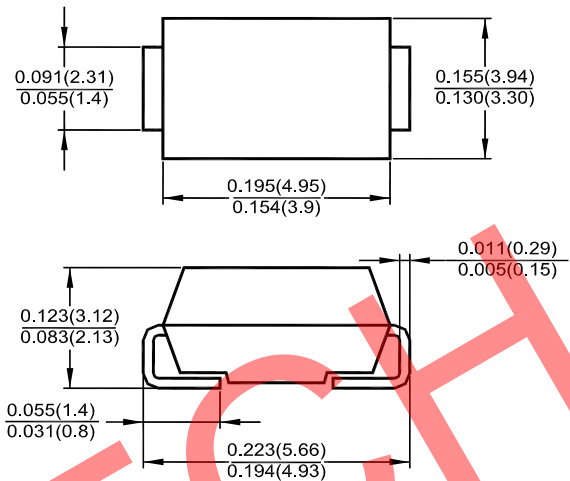
### Features

- High current capability
- High surge current capability
- High reliability
- Low reverse current
- Low forward voltage drop
- Fast switching for high efficiency

### Mechanical Data

- Case: SMB (DO-214AA) molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead: Lead formed for surface mount
- Polarity: color band denotes cathode end
- Mounting position: Any

SMB (DO-214AA)



Dimensions in inches and (millimeters)

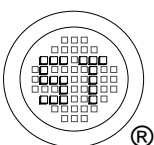
### Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20 %.

| Parameter   | Symbols        | SE2AD         | SE2BD | SE2DD | SE2ED | SE2GD | SE2JD | SE2KD | SE2MD | Units            |
|---|----------------|---------------|-------|-------|-------|-------|-------|-------|-------|------------------|
| Maximum Recurrent Peak Reverse Voltage  | $V_{RRM}$      | 50            | 100   | 200   | 300   | 400   | 600   | 800   | 1000  | V                |
| Maximum RMS Voltage   | $V_{RMS}$      | 35            | 70    | 140   | 210   | 280   | 420   | 560   | 700   | V                |
| Maximum DC Blocking Voltage   | $V_{DC}$       | 50            | 100   | 200   | 300   | 400   | 600   | 800   | 1000  | V                |
| Maximum Average Forward Current $T_a = 55^\circ\text{C}$  | $I_{F(AV)}$    | 2             |       |       |       |       |       |       |       | A                |
| Maximum Peak Forward Surge Current, 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)    | $I_{FSM}$      | 75            |       |       |       |       |       |       |       | A                |
| Maximum Forward Voltage at $I_F = 2\text{ A}$   | $V_F$          | 1.1           |       |       |       | 1.7   |       |       |       | V                |
| Maximum DC Reverse Current at Rated DC Blocking Voltage $T_a = 25^\circ\text{C}$<br>$T_a = 100^\circ\text{C}$ | $I_R$          | 10<br>50      |       |       |       |       |       |       |       | $\mu\text{A}$    |
| Maximum Reverse Recovery Time <sup>1)</sup>   | $t_{rr}$       | 50            |       |       |       | 75    |       |       |       | ns               |
| Typical Junction Capacitance <sup>2)</sup>  | $C_j$          | 50            |       |       |       |       |       |       |       | pF               |
| Junction and Storage Temperature Range  | $T_j, T_{stg}$ | - 65 to + 150 |       |       |       |       |       |       |       | $^\circ\text{C}$ |

<sup>1)</sup> Reverse recovery test conditions:  $I_F = 0.5\text{ A}$ ,  $I_R = 1\text{ A}$ ,  $I_{rr} = 0.25\text{ A}$

<sup>2)</sup> Measured at 1 MHz and applied reverse voltage of 4 V

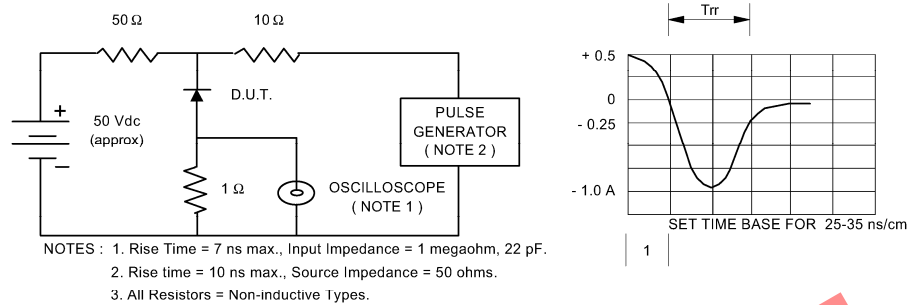


**SEMTECH ELECTRONICS LTD.**  
Subsidiary of Sino-Tech International (BVI) Limited

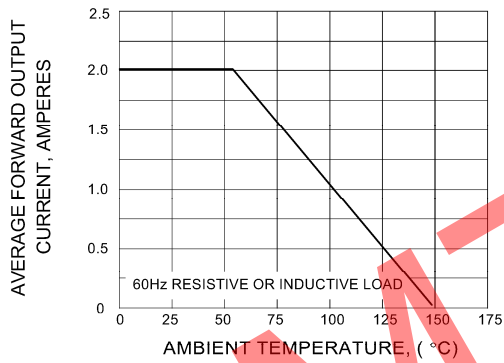


# SE2AD THRU SE2MD

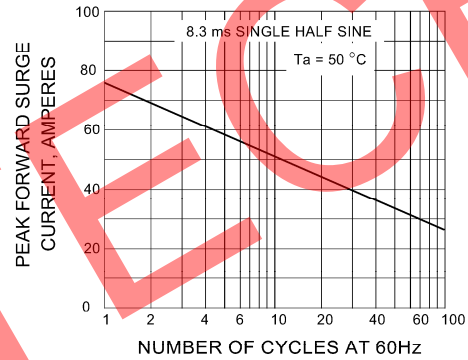
**FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM**



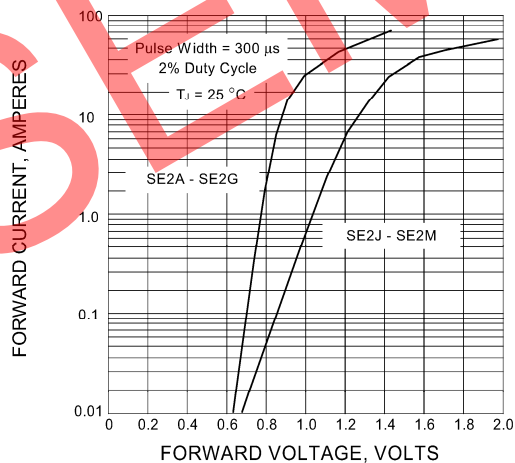
**FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT**



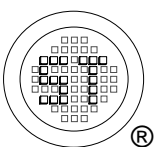
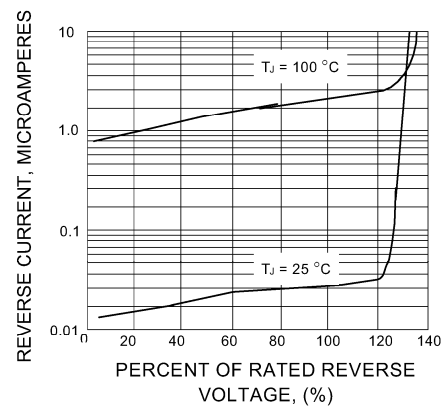
**FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT**



**FIG.4 - TYPICAL FORWARD CHARACTERISTICS**



**FIG.5 - TYPICAL REVERSE CHARACTERISTICS**



**SEMTECH ELECTRONICS LTD.**  
 Subsidiary of Sino-Tech International (BVI) Limited

